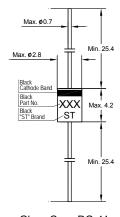
SILICON PLANAR POWER ZENER DIODES

for use in stabilizing and clipping circuits with high power rating.



Glass Case DO-41 Dimensions in mm

Absolute Maximum Ratings ($T_a = 25$ °C)

Parameter	Symbol	Value	Unit				
Power Dissipation	P _{tot}	1 ¹⁾	W				
Junction Temperature	T _j	200	°C				
Storage Temperature Range	T _S	- 65 to + 200	°C				
1) Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.							

Characteristics at T_a = 25 °C

Parameter	Symbol	Max.	Unit			
Thermal Resistance Junction to Ambient Air	R_{thA}	170 ¹⁾	K/W			
Forward Voltage at I _F = 200 mA	V_{F}	1.2	V			
1) Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.						





Turne	Zener Voltage Range 3), 5)		Maximum Zener Impedance 1)		Maximum Reverse Leakage Current		Maximum Surge Current 4)	Maximum Regulator		
Туре	V_{Znom}	V_Z	I _{ZT}	r_{ZJT}	r_{ZJK}	at I_{ZK}	I_R	at V_{R}	at T _a = 25 °C	Current 2)
	V	V	mA	Ω	Ω	mA	μA	V	I _{ZSM} (mA)	I _{ZM} (mA)
1N4727A	3	2.853.15	83	10	400	1	150	1	1375	275
1N4728A	3.3	3.133.47	76	10	400	1	150	1	1375	275
1N4729A	3.6	3.423.78	69	10	400	1	100	1	1260	252
1N4730A	3.9	3.74.1	64	9	400	1	100	1	1190	234
1N4731A	4.3	4.084.52	58	9	400	1	50	1	1070	217
1N4732A	4.7	4.464.94	53	8	500	1	10	1	970	193
1N4733A	5.1	4.845.36	49	7	550	1	10	1	890	178
1N4734A	5.6	5.325.88	45	5	600	1	10	2	810	162
1N4735A	6.2	5.896.51	41	2	700	1	10	3	730	146
1N4736A	6.8	6.467.14	37	3.5	700	1	10	4	660	133
1N4737A	7.5	7.127.88	34	4	700	0.5	10	5	605	121
1N4738A	8.2	7.798.61	31	4.5	700	0.5	10	6	550	110
1N4739A	9.1	8.649.56	28	5	700	0.5	10	7	500	100
1N4740A	10	9.510.5	25	7	700	0.25	10	7.6	454	91
1N4741A	11	10.4511.55	23	8	700	0.25	5	8.4	414	83
1N4742A	12	11.412.6	21	9	700	0.25	5	9.1	380	76
1N4743A	13	12.3513.65	19	10	700	0.25	5	9.9	344	69
1N4744A	15	14.2515.75	17	14	700	0.25	5	11.4	304	61
1N4745A	16	15.216.8	15.5	16	700	0.25	5	12.2	285	57
1N4746A	18	17.118.9	14	20	750	0.25	5	13.7	250	50
1N4747A	20	1921	12.5	22	750	0.25	5	15.2	225	45
1N4748A	22	20.923.1	11.5	23	750	0.25	5	16.7	205	41
1N4749A	24	22.825.2	10.5	25	750	0.25	5	18.2	190	38
1N4750A	27	25.6528.35	9.5	35	750	0.25	5	20.6	170	34
1N4751A	30	28.531.5	8.5	40	1000	0.25	5	22.8	150	30
1N4752A	33	31.3534.65	7.5	45	1000	0.25	5	25.1	135	27
1N4753A	36	34.237.8	7	50	1000	0.25	5	27.4	125	25
1N4754A	39	37.0540.95	6.5	60	1000	0.25	5	29.7	115	23
1N4755A	43	40.8545.15	6	70	1500	0.25	5	32.7	110	22
1N4756A	47	44.6549.35	5.5	80	1500	0.25	5	35.8	95	19
1N4757A	51	48.4553.55	5	95	1500	0.25	5	38.8	90	18
1N4758A	56	53.258.8	4.5	110	2000	0.25	5	42.6	80	16
1N4759A	62	58.965.1	4	125	2000	0.25	5	47.1	70	14
1N4760A	68	64.671.4	3.7	150	2000	0.25	5	51.7	65	13
1N4761A	75	71.2578.75	3.3	175	2000	0.25	5	56	60	12
1N4762A	82	77.986.1	3	200	3000	0.25	5	62.2	55	11
1N4763A	91	86.4595.55	2.8	250	3000	0.25	5	69.2	50	10
1N4764A	100	95105	2.5	350	3000	0.25	5	76	45	9

¹⁾ The Zener Impedance is derived from the 60 Hz AC voltage which results when an AC current having an RMS value equal to 10% of the Zener Current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK}. Zener Impedance is measured at two points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

⁵⁾ Tested with pulses tp = 20 ms.



SEMTECH ELECTRONICS LTD.

(Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)







Dated: 12/06/2007

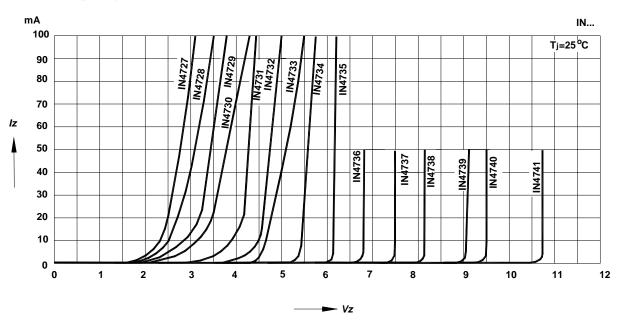
²⁾ Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.

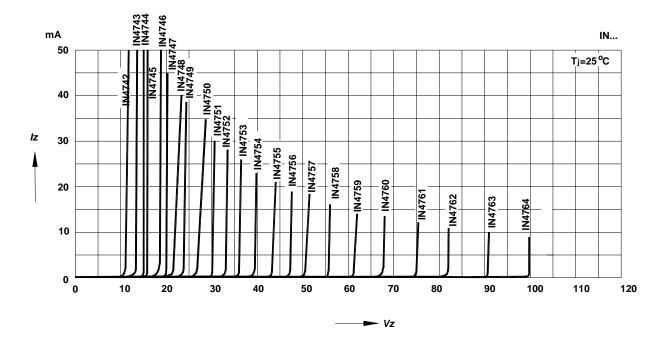
³⁾ Measured under thermal equilibrium and DC test conditions.

⁴⁾ The rating listed in the electrical characteristics table is maximum peak, non-repetitive, reverse surge current of 1/2 square wave or equivalent sine wave pulse of 1/120 second duration superimposed on the test current I_{ZT}.

Breakdowm characteristics

Tj=constant(pulsed)







SEMTECH ELECTRONICS LTD.

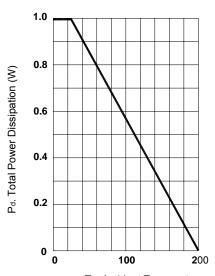
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T_A, Ambient Temperature Fig. 1 Power Dissipation vs Ambient Temperature

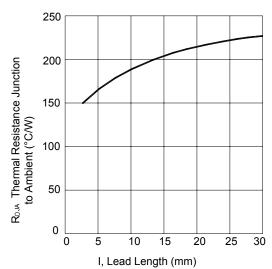


Fig. 2 Typical Thermal Resistance vs. Lead Length

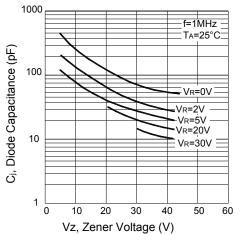


Fig. 3 Junction Capacitance vs Zener Voltage

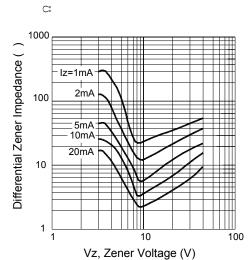


Fig. 4 Typical Zener Impedance vs. Zener Voltage







